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XP152A12C0MR

ETR1121_001

JISH

Power MOSFET

GENERAL DESCRIPTION

The XP152A12C0MR is a P-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics. Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

In order to counter static, a gate protect diode is built-in.

The small SOT-23 package makes high density mounting possible.

■ APPLICATIONS

- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

FEATURES

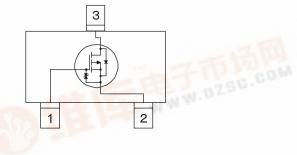
Low On-State Resistance : $Rds(on) = 0.3 \Omega @ Vgs = -4.5V$: $Rds(on) = 0.5 \Omega @ Vgs = -2.5V$

Ultra High-Speed Switching Gate Protect Diode Built-in Driving Voltage :-2.5V P-Channel Power MOSFET DMOS Structure Small Package : SOT-23

PIN CONFIGURATION



EQUIVALENT CIRCUIT



P-channel MOSFET (1 device built-in)

c.com

■ PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1	G	Gate
2	S	Source
3	D	Drain

ABSOLUTE MAXIMUM RATINGS

Ta = 2						
PARAMETER	SYMBOL	RATINGS	UNITS			
Drain - Source Voltage	Vdss	-20	V			
Gate - Source Voltage	Vgss	±12	V			
Drain Current (DC)	ld	-0.7	А			
Drain Current (Pulse)	ldp	-2.8	А			
Reverse Drain Current	ldr	-0.7	А			
Channel Power Dissipation *	Pd	0.5	W			
Channel Temperature	Tch	150	°C			
Storage Temperature Range	Tstg	-55~150	°C			

* When implemented on a ceramic PCB

XP152A12C0MR

■ ELECTRICAL CHARACTERISTICS

DC Characteristics

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds= -20V, Vgs= 0V	-	-	-10	μA
Gate-Source Leak Current	lgss	Vgs= \pm 12V, Vds= 0V	-	-	±10	μA
Gate-Source Cut-Off Voltage	Vgs(off)	Id= -1mA, Vds= -10V	-0.5	-	-1.2	V
Drain-Source On-State Resistance *1	Rds(on)	Id= -0.4A, Vgs= -4.5V	-	0.23	0.30	Ω
		ld= -0.4A, Vgs= -2.5V	-	0.37	0.50	Ω
Forward Transfer Admittance *1	Yfs	ld= -0.4A, Vds= -10V	-	1.5	-	S
Body Drain Diode Forward Voltage	Vf	lf= -0.7A, Vgs= 0V	-	-0.8	-1.1	V

*1 Effective during pulse test.

Dynamic Characteristics

Ta = 25℃

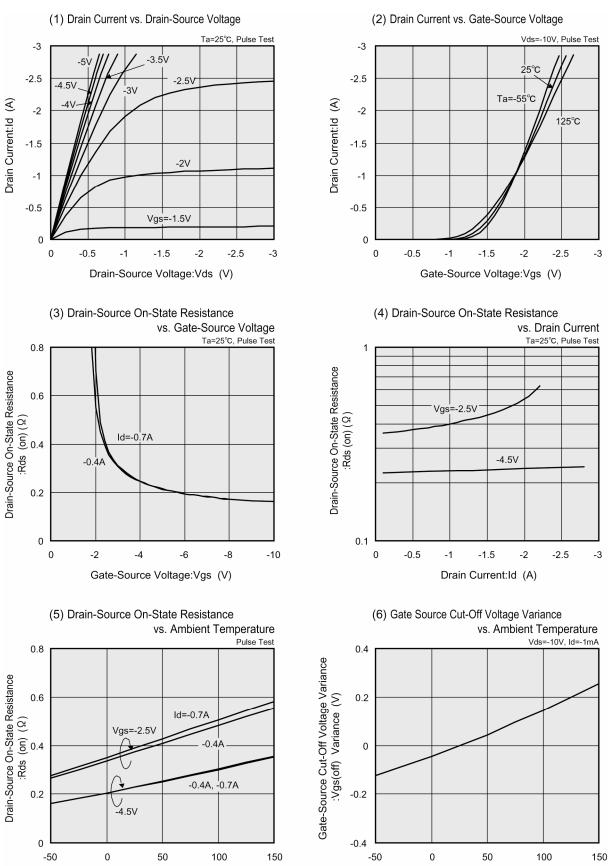
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds= -10V, Vgs=0V f= 1MHz	-	180	-	pF
Output Capacitance	Coss		-	120	-	pF
Feedback Capacitance	Crss		-	60	-	pF

Switching Characteristics

Switching CharacteristicsTa = 25°C						
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs= -5V, Id= -0.4A Vdd= -10V	-	5	-	ns
Rise Time	tr		-	20	-	ns
Turn-Off Delay Time	td (off)		-	55	-	ns
Fall Time	tf		-	70	-	ns

Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	Rth (ch-a)	Implement on a ceramic PCB	-	250	-	°C/W



Ambient Temperature:Topr (°C)

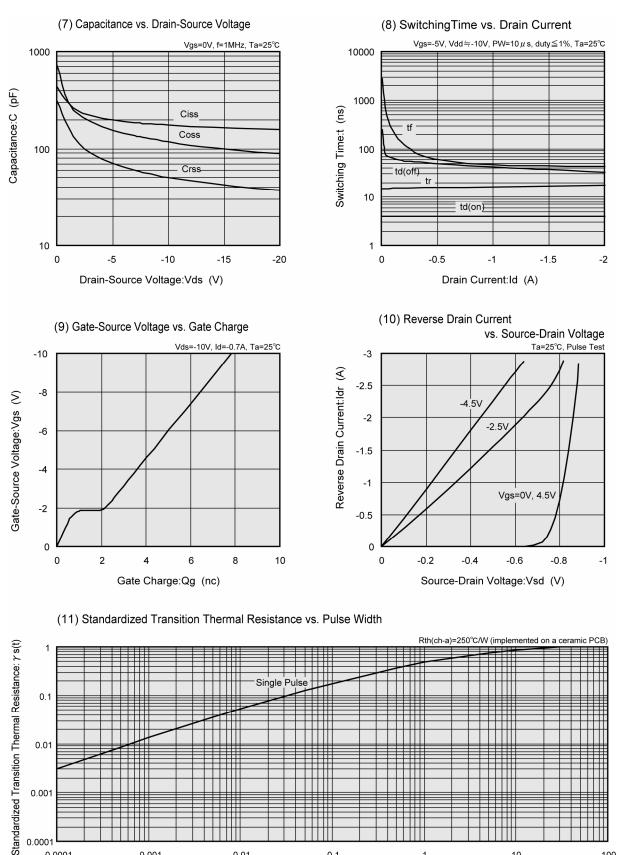
■ TYPICAL PERFOMANCE CHARACTERISTICS

XP152A12C0MR

0.0001

0.0001

■TYPICAL PERFOMANCE CHARACTERISTICS (Continued)



0.01 10 0.001 0.1 1

100

Pulse Width: PW (s)

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